

DECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATION

DOCKET NO. CS01-193

As a below named Inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name;

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled Method To Selectively Form Poly SiGe P Type Electrode And Polysilicon N Type Electrode Through Planarization

the specification of which (check one)

X is attached hereto.

was filed on _____

Application Serial No. _____

and was amended on _____

(if applicable)

I hereby state that I have reviewed and understand the contents of the above Identified specification including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose information which is material to the examination of this application in accordance with Title 37, Code of Federal Regulations, §1.56(a).

I hereby claim foreign priority benefits under Title 35, United States Code §119 of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

Prior Foreign Application(s)

Priority Claimed:

(Number)	(Country)	(Day/Month/Year Filed)
(Number)	(Country)	(Day/Month/Year Filed)

I hereby claim the benefit under Title 35, United States Code §120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, §112, I acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, §1.56(a) which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

(Application Serial No.)	(Filing Date)	(Status) (patented, pending, abandoned)
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I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

POWER OF ATTORNEY: As a named inventor, I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith. (list name & registration no.)

GEORGE O. SAILE. (Reg. No. 19,572), STEPHEN B. ACKERMAN (Reg. No. 37,761)

Send Correspondence to: 28 DAVIS AVENUE, POUGHKEEPSIE; NEW YORK 12603

Direct telephone Calls to: (name & telephone number) GEORGE O. SAILE NEW YORK 845 452 5863

Tze Ho Chan
Full name of sole or first inventor

02/09/2003 Sept. 2, 2003
Date

[Signature]
Inventor's Signature

BLK 789, #12-641 WOODLANDS AVE 6, SINGAPORE 730789
Residence

HONG KONG
Citizenship

Chartered Semiconductor Manufacturing Ltd., 60 Woodlands Ind. Park D, Street 2, Singapore 738406
Post Office Address

DOCKET NO. **CS01-193**
SEP 18 03

Mousumi Bhat

Full name of second inventor

Date

Mousumi Bhat
Inventor's signature

12 WOODGROVE DRIVE #04-61, SINGAPORE - 738212 Singapore
Residence

USA

Citizenship

Chartered Semiconductor Manufacturing Ltd., 60 Woodlands Ind. Park D, Street 2, Singapore 738406 Singapore
Post Office Address

Jeffrey Chee

Full name of third inventor

Date

22 Sep 03

Jeffrey Chee
Inventor's signature

BLK 501C Wallington Circle #09-62 Singapore 753501 Singapore
Residence

Singapore

Citizenship

Chartered Semiconductor Manufacturing Ltd., 60 Woodlands Ind. Park D, Street 2, Singapore 738406 Singapore

Post Office Address

Full name of fourth inventor

Date

Inventor's signature

Residence

Citizenship

Post Office Address

Full name of fifth inventor

Date

Inventor's signature

Residence

Citizenship

Post Office Address

Full name of sixth inventor

Date

Inventor's signature

Residence

Citizenship

Post Office Address